Diode Semiconductor Device - Page 1 of 1



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~	sure Material:
Glass	-
	all Length:
) inches
Term	ninal Length:
1.250) inches
Over	all Diameter:
0.075	5 inches
Fund	tion For Which Designed:
Zene	r diode
Joint	t Electronic Device Engineering Council/jedec/case Outline Designation
Do-2	04ah
Mou	nting Method:
Term	inal
Feat	ures Provided:
Herm	netically sealed case
Semi	iconductor Material:
Silico	n
Volta	age Rating In Volts Per Characteristic:
60.0	regulator voltage
Volta	age Tolerance In Percent:
-0.5/-	+0.5
Curre	ent Rating Per Characteristic:
2.10	milliamperes all primaries horsepower metric
Powe	er Rating Per Characteristic:
500.0) milliwatts small-signal input power, common-collector absolute
Maxi	mum Operating Tempurature Per Measurement Point:
200.0) degrees celsius ambient air
Term	ninal Type And Quantity:
2 uni	nsulated wire lead
Spec	ification Data:
-	1-release5566 professional/industrial association specification
	f Life:
N/a	
	Of Measure:
Dem	ilitarization:
No	
Fiig:	
A110	
ATTU	